

NTE7125 & NTE7126 Integrated Circuit Switching Regulator

Description:

The NTE7125 and NTE7126 are integrated circuits in a 12-Lead SIP type package incorporating all the power switching, amplifier, error detection, and overcurrent protection circuits required in a self-excitation type semi-regulated off-line switching regulator. As a result, these devices can be used in the design of switching power supplies with a minimal number of external components. Furthermore, the adoption of MOSFET power switching elements supports a higher oscillation frequency than possible with bi-polar transistors. This allows smaller pulse transformers and capacitors to be used, making it possible to construct miniature power supply systems.

Features:

- Power MOSFET Devices
- Ideal for Semi-Regulated Control Switching Supplies
- Error Detection Circuit On-Chip (40.5V ±0.5V Set Reference Voltage)
- Overcurrent Protection Circuit On-Chip
- Higher Oscillation Frequency allows the use of Smaller Pulse Transformers
- IMST Substrate acts as an Electromagnetic Shield, making Low-Noise Designs Possible

Applications:

- CRT/CTV Power Supplies
- Office Automation Equipment Power Supplies

Absolute Maximum Ratings: (T_A = +25°C unless otherwise specified)

Operating Substrate Temperature (Recommended value is +105°C), T _{Cmax}	+115°C
AC Input Voltage, V _{AC}	140V _{rms}
Operating Temperature Range, T _{opr}	-10° to +85°C
Storage Temperature Range, T _{stg}	-30° to +115°C
Maximum Output Power (V _O = 135V), W _{Omax}	
NTE7125	110W
NTE7126	145W

TR1

Drain Current, I _D	
NTE7125	6A
NTE7126	8A
Pulse Drain Current, I _D (pulse)	20A
Drain Reverse Current, I _{DR}	6A
Gate-Source Voltage, V _{GSS}	±30V

Absolute Maximum Ratings (Cont'd): ($T_A = +25^\circ\text{C}$ unless otherwise specified)

TR1 (Cont'd)

Allowable Power Dissipation, P_D	78.1W
Chip Junction Temperature, T_{Jmax}	+150°C
Thermal Resistance, Junction-to-Case, R_{thJ-C}	1.6°C/W

ZD1

Allowable Power Dissipation, P_{ZD1}	500mW
Chip Junction Temperature, $T_{J(ZD1)max}$	+125°C
Thermal Resistance, Junction-to-Case, $R_{thJ-C(ZD1)}$	0.2°C/W

Allowable Operating Ranges: ($T_A = +25^\circ\text{C}$ unless otherwise specified)

Pin4 Input Voltage, V_4	± 6 to $\pm 24\text{V}$
Oscillator Frequency, f_{OSC}	20 to 120kHz

Operating Characteristics: ($T_A = +25^\circ\text{C}$, $T_C = +25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Output Voltage Setting		$I_{IN} = 8\text{mA}$	40.0	40.5	41.0	V
Output Voltage Temperature Coefficient		$T_C = 0^\circ$ to $+105^\circ\text{C}$, $I_{IN} = 8\text{mA}$	-	7	-	mV/°C
TR1						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D = 10\text{mA}$, $V_{GS} = 0\text{V}$	500	-	-	V
Gate-Source Cutoff Voltage	$V_{GS(off)}$	$I_D = 1\text{mA}$, $V_{DS} = 10\text{V}$	2.0	-	3.0	V
ON Resistance NTE7125 NTE7126	$R_{DS(on)}$	$I_D = 2.5\text{A}$, $V_{GS} = 10\text{V}$	-	1.4 0.8	1.8 1.8	Ω Ω
Input Capacitance	C_{iss}	$V_{DS} = 10\text{V}$, $V_{GS} = 0\text{V}$, $f = 1\text{MHz}$	-	800	-	pF
ZD1						
Zener Voltage	V_Z	$I_Z = 5\text{mA}$	23.7	-	26.3	V

Pin Connection Diagram
(Front View)



